

isc Silicon NPN Power Transistors

TIP41F

DESCRIPTION

- DC Current Gain -h_{FE} = 30(Min)@ I_C= 0.3A
- · Collector-Emitter Sustaining Voltage-
- : V_{CEO(SUS)} = 160V(Min)
- Complement to Type TIP42F
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

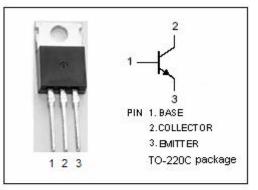
Designed for use in general purpose amplifer and switching applications

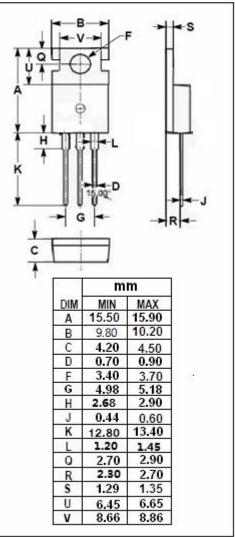
ABSOLUTE MAXIMUM RATINGS(Ta=25℃) SYMBOL VALUE UNIT PARAMETER Collector-Base Voltage 200 V VCBO V_{CEO} Collector-Emitter Voltage 160 V VEBO **Emitter-Base Voltage** 5 V **Collector Current-Continuous** I_{C} 6 А **Collector Current-Peak** Ісм 10 A **Base Current** 3 А I_{B} **Collector Power Dissipation** 65 Tc=25℃ Pc W **Collector Power Dissipation** 2 Ta=25℃ Junction Temperature Ti °C 150 °C Storage Temperature Range -65~150 Tstg

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	1.92	°C/W
R _{th j-a}	Thermal Resistance, Junction to Ambient	62.5	°C/W

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ELECTRICAL CHARACTERISTICS

 $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
Vceo(sus)	Collector-Emitter Sustaining Voltage	I _C = 30mA; I _B = 0	160		V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 6A; I _B = 1.5A		1.5	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = 6A; V _{CE} = 4V		2.0	V
I _{CES}	Collector Cutoff Current	V _{CE} = 200V; V _{BE} = 0		0.4	mA
I _{CEO}	Collector Cutoff Current	V _{CE} = 90V; I _B = 0		0.7	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0		1.0	mA
h _{FE-1}	DC Current Gain	Ic= 0.3A; Vce= 4V	30		
h _{FE-2}	DC Current Gain	I _C = 3A; V _{CE} = 4V	15		
f⊤	Current-Gain—Bandwidth Product	I _C = 0.5A ; V _{CE} = 10V	3		MHz

Switching Time

ton	Turn-On Time	I _C = 6A; I _{B1} = -I _{B2} = 0.6A;	0.6	μ S
toff	Turn-Off Time	$V_{BE(off)}$ = 4V, RL= 5 Ω	1.0	μ S

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